

EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	4207	257/347.ccls.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/05/18 21:03
L2	808	257/e29.117.ccls.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/05/18 21:03
L3	1584	257/e29.137.ccls.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/05/18 21:03
L4	1024	257/e29.273.ccls.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/05/18 21:03
L5	217	257/e29.202.ccls.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/05/18 21:03
L6	3	257/e29.145.ccls.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/05/18 21:03
L7	1025	257/e29.147.ccls.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/05/18 21:03

L8	218	257/e31.096.ccls.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/05/18 21:03
L9	215	257/e33.061.ccls.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/05/18 21:04
L10	392	257/e31.095.ccls.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/05/18 21:04
S2	660	257/e29.117.ccls.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/05/01 14:37
S3	2	257/e29.145.ccls.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/05/01 14:37
S4	34	("4591848" "5132819" "5457474" "5477073" "5567959" "5644147" "5807772" "5814834" "5818070" "5821137" "5834797" "5917199" "5917221" "5929527" "5956011" "6010923" "6037924" "6072193" "6081131" "6150283" "6153893" "6197624" "6198133" "6204519" "6207971" "6215154" "6380011" "6392628" "6396078" "6462723" "6512271" "6569716" "6603453" "6608613"). PN.	US-PGPUB; USPAT; USOCR	OR	ON	2008/05/01 14:38

S5	1	(light near shield) near (titanium near oxide)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/05/02 11:38
S6	40	(light near shield) same (titanium near oxide)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/05/02 11:39
S7	2	("20020089616").PN.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2008/05/02 11:46
S10	2	("20010034088").PN.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2008/05/02 16:36
S11	212	("thin film transistor" or tft) same ((liquid near crystal) near (electroluminescent or el))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/05/05 10:16
S12	3824	257/347.ccls.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/05/05 10:54
S13	26	capacitor near electrode near copper	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/05/06 14:14
S14	13	((("20030143794") or ("6787407") or ("20010034088") or ("6821827") or ("20050054181") or ("20030219934") or ("6908796") or ("20020089616") or ("6587165"))).PN.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2008/05/06 14:56

S15	376	257/e27.116.ccls.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/11/03 11:37
S16	3566	((SHUNPEI) near2 (YAMAZAKI)).INV.	US-PGPUB; USPAT	OR	ON	2008/11/03 11:41
S17	338	((SHUNPEI) near2 (YAMAZAKI)).INV. and ("droplet discharge" or "ink- jet")	US-PGPUB; USPAT	OR	ON	2008/11/03 11:42
S18	13	((("20070132377") or ("20070082443") or ("20070040971") or ("20070096096") or ("7176069") or ("7202497") or ("7192865")).PN.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2008/11/03 11:47
S19	8	((("5948705") or ("6221140") or ("6043149") or ("5706064")).PN.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2008/11/03 11:53
S20	2	"US 20070085938"	US-PGPUB; USPAT; USOCR; DERWENT	OR	ON	2008/11/03 12:18
S21	7	("4712874" "5153753" "5321535" "5321538" "5503932" "5517343" "5520855").PN.	US-PGPUB; USPAT; USOCR	OR	ON	2008/11/03 12:37
S22	16	((("20020089616") or ("6365917") or ("5706064") or ("4389481") or ("5329390") or ("20010034088") or ("20010014528") or ("6461914")).PN.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2008/11/03 17:16
S23	2	"US 20070085938"	US-PGPUB; USPAT; USOCR; DERWENT	OR	ON	2008/11/03 19:07
S25	85	(copper near wiring) same (tft or "thin film transistor")	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/11/03 19:22

S26	81	(amorphous near gate) same (tft or "thin film transistor")	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/11/03 19:50
S27	4003	257/347.ccls.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/11/03 20:18
S28	733	257/e29.117.ccls.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/11/03 20:19
S29	1461	257/e29.137.ccls.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/11/03 20:19
S30	950	257/e29.273.ccls.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/11/03 20:19
S31	203	257/e29.202.ccls.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/11/03 20:19
S32	3	257/e29.145.ccls.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/11/03 20:19
S33	944	257/e29.147.ccls.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/11/03 20:19

S34	212	257/e31.096.ccls.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/11/03 20:20
S35	1699	257/e33.061.ccls.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/11/03 20:20
S36	365	257/e31.095.ccls.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/11/03 20:20
S37	458	("thin film transistor" or tft) same ((liquid near crystal or LCD) near (electroluminescent or el))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/05/15 18:39
S40	2	("thin film transistor" or tft) with (liquid near crystal or LCD) with (electroluminescent or el) with (insulat\$3 or dielectric) with (opening or recess or window or via or throughhole or trench)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/05/15 18:41
S41	15	("thin film transistor" or tft) same (liquid near crystal or LCD) same (electroluminescent or el) same (insulat\$3 or dielectric) with (opening or recess or window or via or throughhole or trench)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/05/15 18:41
S42	36	("thin film transistor" or tft) near (liquid near crystal or LCD) near (electroluminescent or el)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/05/15 18:44

S43	198	("thin film transistor" or tft) same (liquid near crystal or LCD) same (electroluminescent or el) same (insulat\$3 or dielectric) with (metal or interconnect or conduct\$3 or via or plug)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/05/18 17:24
S44	251	("thin film transistor" or tft) same (liquid near crystal or LCD) same (electroluminescent or el) same (insulat\$3 or dielectric) same (metal or interconnect or conduct\$3 or via or plug)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/05/18 17:25

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